

System $\text{SrGa}_2\text{S}_4\text{--LaGaS}_3$

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Abstract—Phase relations in the $\text{SrGa}_2\text{S}_4\text{--LaGaS}_3$ system were studied by physicochemical analysis, and the $\text{SrGa}_2\text{S}_4\text{--LaGaS}_3$ phase diagram was mapped out. The system was found to contain the quaternary compound $\text{SrLaGa}_3\text{S}_7$, which melts congruently at 1290 K and has a tetragonal structure. The composition ranges of the SrGa_2S_4 - and $\text{SrLaGa}_3\text{S}_7$ -based solid solutions were determined.

In earlier studies [1, 2], the $\text{EuGa}_2\text{S}_4\text{--LaGaS}_3$ and $\text{CaGa}_2\text{S}_4\text{--LaGaS}_3$ systems were found to contain quaternary compounds with the MLaGa_3S_7 stoichiometry. These compounds were shown to be wide-gap *p*-type semiconductors [3]. $\text{CaLaGa}_3\text{S}_7$ has a tetragonal structure with $a = 9.50 \text{ \AA}$ and $c = 6.16 \text{ \AA}$ [4].

In this communication, we report our results on the $\text{SrGa}_2\text{S}_4\text{--LaGaS}_3$ system.

SrGa_2S_4 (S_1) is known to crystallize in the orthorhombic system with $a = 20.64 \text{ \AA}$, $b = 20.49 \text{ \AA}$, and $c = 12.21 \text{ \AA}$ ($\rho_{\text{meas}} = 3.62 \text{ g/cm}^3$, $\rho_x = 3.64 \text{ g/cm}^3$) [5]. LaGaS_3 (S_4) has a monoclinic structure with $a = 10.33 \text{ \AA}$, $b = 12.82 \text{ \AA}$, $c = 10.56 \text{ \AA}$, and $\gamma = 98.90^\circ$ ($\rho_{\text{meas}} = 4.32 \text{ g/cm}^3$, $\rho_x = 4.35 \text{ g/cm}^3$) [6, 7].

According to Petere and Baglie [8], SrGa_2S_4 melts congruently at 1400 K. LaGaS_3 was reported to form peritectically [7].

In our preparations, SrGa_2S_4 and LaGaS_3 were pre-synthesized from SrS , Ga_2S_3 , and La_2S_3 . Quaternary alloys were prepared by reacting appropriate mixtures at 1200 K for 8–10 h in evacuated quartz tubes, followed by homogenization at 900–950 K for 130–135 h, depending on composition. The samples ranged in color from yellow to yellow-orange.

The alloys were characterized by differential thermal analysis (NTR-70 unit), x-ray diffraction (DRON-3 powder diffractometer, CuK_α radiation), microstructural analysis (MIM-7 optical microscope), microhardness tests, and density measurements.

The temperature was measured with an accuracy of $\pm 5 \text{ K}$. Lattice parameters were determined to within $\pm 0.01 \text{ \AA}$. The accuracy in density and microhardness measurements was $\pm 10\%$ or better.

Microstructural examination showed that the melted alloys containing 0–4 and 47–54 mol % LaGaS_3 were single-phase, with sharp grain boundaries (Fig. 1). The other alloys were two-phase. The same was evidenced by microhardness measurements: the measured microhardness values were found to fall in three distinct

ranges, 3000–3120, 2740–2890, and 3090–3130 MPa, corresponding to the α -phase (SrGa_2S_4 -based solid solution), β -phase ($\text{SrLaGa}_3\text{S}_7$ -based solid solution), and LaGaS_3 .

The $\text{SrGa}_2\text{S}_4\text{--LaGaS}_3$ phase diagram constructed on the basis of the present results is displayed in Fig. 2b. The system contains the quaternary compound $\text{SrLaGa}_3\text{S}_7$ (S_2) and narrow composition ranges of the α - and β -phases. $\text{SrLaGa}_3\text{S}_7$ melts congruently at 1293 K.

The $\text{SrGa}_2\text{S}_4\text{--LaGaS}_3$ phase diagram can be regarded as consisting of two partial phase diagrams: $\text{SrGa}_2\text{S}_4\text{--SrLaGa}_3\text{S}_7$ and $\text{SrLaGa}_3\text{S}_7\text{--LaGaS}_3$. SrGa_2S_4 and $\text{SrLaGa}_3\text{S}_7$ form a eutectic at 25 mol % LaGaS_3 with the melting point at 1010 K. The composition range of the α -phase extends to 10 mol % LaGaS_3 at 1010 K. With decreasing temperature, the solubility of $\text{SrLaGa}_3\text{S}_7$ in SrGa_2S_4 decreases to 4 mol %, which leads to precipitation of the β -phase in the form of small platelets embedded in the α -phase matrix. $\text{SrLaGa}_3\text{S}_7$ exists in the composition range 47–54 mol % LaGaS_3 and has a tetragonal structure with $a = 9.45\text{--}9.54 \text{ \AA}$ and $c = 6.14\text{--}6.18 \text{ \AA}$.

The $\text{SrLaGa}_3\text{S}_7\text{--LaGaS}_3$ join is nonpseudobinary, because of the incongruent melting of LaGaS_3 . This

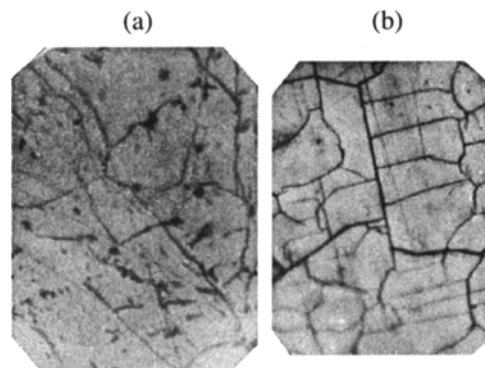


Fig. 1. Microstructures of $\text{SrGa}_2\text{S}_4\text{--LaGaS}_3$ alloys containing (a) 4 and (b) 50 mol % LaGaS_3 ; $\times 57.5$.

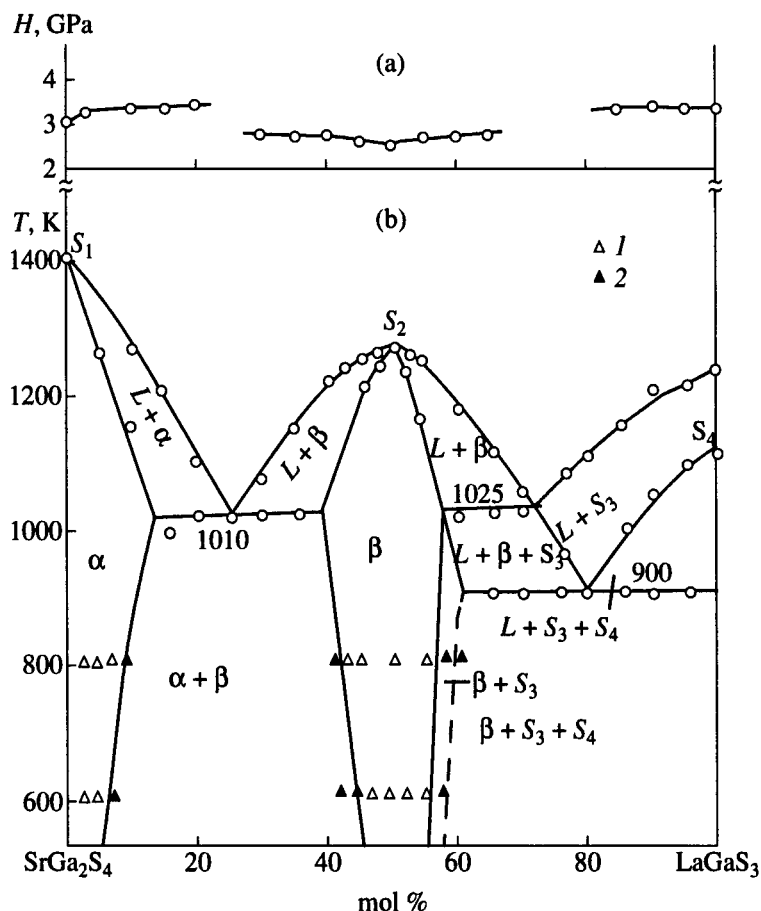


Fig. 2. (a) Composition dependence of microhardness; (b) SrGa_2S_4 – LaGaS_3 phase diagram: (1) single-phase alloys, (2) two-phase alloys; $S_1 = \text{SrGa}_2\text{S}_4$, $S_2 = \text{SrLaGa}_3\text{S}_7$, $S_3 = \text{La}_6\text{Ga}_{10/3}\text{S}_{14}$, $S_4 = \text{LaGaS}_3$.

join intersects two primary-crystallization fields—those of the β -phase and $\text{La}_6\text{Ga}_{10/3}\text{S}_{14}$. The corresponding branches of the liquidus intersect at 71.5 mol % LaGaS_3 (1025 K). The primary crystallization of S_3 is followed by the three-phase peritectic reaction $L + S_3 = S_4$.

Note that, in the composition range 70–100 mol % SrGa_2S_4 , liquid quenching yielded glassy alloys. The DTA curves of these alloys showed prominent endotherms between 840 and 850 K. According to DTA data, the glass-transition temperature of the SrGa_2S_4 -rich alloys rises from 820 to 830 K with increasing $\text{SrLaGa}_3\text{S}_7$ content. The glass of composition SrGa_2S_4 was found to crystallize most readily.

X-ray diffraction data demonstrate that $\text{SrLaGa}_3\text{S}_7$ is isostructural with $\text{CaLaGa}_3\text{S}_7$ and has a tetragonal structure with $a = 9.54 \text{ \AA}$ and $c = 6.18 \text{ \AA}$ ($V = 562.45 \text{ \AA}^3$, sp. gr. $P4_2/m$, $Z = 2$).

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